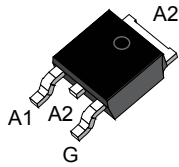


4 A Sensitive gate SCR in DPAK package


DPAK

Features

- 4 A Triac
- Sensitive SCR: $I_{GT} = 200 \mu\text{A}$
- $V_{DRM} / V_{RRM} = 600 \text{ V}$ and $V_{DSM} / V_{RSM} = 750 \text{ V}$
- 125 °C maximum junction temperature T_j
- DPAK SMD package
- Halogen-free molding, lead-free plating
- ECOPACK2 compliant

Application

- Actuators
- Igniters
- Inrush current limiting circuits

Product status link

[X0402MB](#)

Product summary

$I_{T(RMS)}$	4 A
V_{DSM}/V_{RSM}	750 V
I_{GT}	200 μA
$T_j \text{ max.}$	125 °C

Description

The X04 series is 4 A SCR housed in compact SMD DPAK package. This highly sensitive device is suited to home appliances or power tools and industrial systems and drives loads up to 4 A.

1 Characteristics

Table 1. Absolute maximum ratings (limiting values)

Symbol	Parameter	Value	Unit
$I_{T(RMS)}$	RMS on-state current (full sine wave)	$T_c = 114\text{ °C}$	4 A
I_{TAV}	RMS on-state average current (full sine wave)	$T_c = 114\text{ °C}$	2.5 A
I_{TSM}	Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C)	$t = 8.3\text{ ms}$	33 A
		$t = 10\text{ ms}$	30 A
I^2t	I^2t value for fusing	$t_p = 10\text{ ms}$	9 A ² s
di/dt	Critical rate of rise of on-state current, $I_G = 2 \times I_{GT}$, $t_r \leq 100\text{ ns}$, $f = 60\text{ Hz}$	$T_j = 125\text{ °C}$	50 A/ μ s
V_{DRM}/V_{RRM}	Repetitive peak off-state voltage	$T_j = 125\text{ °C}$	600 V
V_{DSM}/V_{RSM}	Non Repetitive peak off-state voltage, 10 ms		750 V
I_{GM}	Maximum peak gate current	$t_p = 20\text{ }\mu\text{s}$, $T_j = 125\text{ °C}$	1.2 A
P_{GM}	Maximum gate power dissipation		0.5 W
T_{stg}	Storage temperature range		-40 to +125 °C
T_j	Operating junction temperature range		-40 to +125 °C
T_L	Maximum lead temperature for soldering during 10 s		260 °C

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

Symbol	Test conditions	Value	Unit
$I_{GT}^{(1)}$	$V_D = 12\text{ V}$, $R_L = 140\text{ }\Omega$	Max.	200 μ A
V_{GT}		Max.	0.8 V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3\text{ k}\Omega$	$T_j = 125\text{ °C}$	Min. 0.1 V
V_{RGM}	$I_{RG} = 10\text{ }\mu\text{A}$	Max.	8 V
I_L	$I_G = 1.2 \times I_{GT}$	Max.	6 mA
$I_H^{(2)}$	$I_T = 500\text{ mA}$, gate open	Max.	5 mA
$dV/dt^{(2)}$	$V_D = 67\% V_{DRM}$, $R_{GK} = 1\text{ k}\Omega$	$T_j = 110\text{ °C}$	Min. 10 V/ μ s

1. For both polarities of OUT pin referenced to COM pin.

2. For both polarities of A2 referenced to A1.

Table 3. Static characteristics

Symbol	Test conditions	T_j	Value	Unit
$V_{TM}^{(1)}$	$I_{TM} = 8\text{ A}$, $t_p = 380\text{ }\mu\text{s}$	25 °C	Max. 1.8	V
$V_{TO}^{(1)}$	Threshold voltage	125 °C	Max. 0.85	V
$R_D^{(1)}$	Dynamic resistance	125 °C	Max. 100	m Ω
I_{DRM}/I_{RRM}	$V_D = V_{DRM}$; $V_R = V_{RRM}$; $R_{GK} = 1\text{ k}\Omega$	25 °C	Max. 5	μ A
		125 °C	1	mA

1. For both polarities of A2 referenced to A1.

Table 4. Thermal resistance

Symbol	Parameter		Value	Unit
$R_{th(j-c)}$	Junction to case	Max.	3	°C/W
$R_{th(j-a)}$	Junction to ambient: $S_{CU} = 0.5 \text{ cm}^2$	Typ.	70	°C/W

1.1 Characteristics (curves)

Figure 1. Maximum average power dissipation versus on-state RMS current

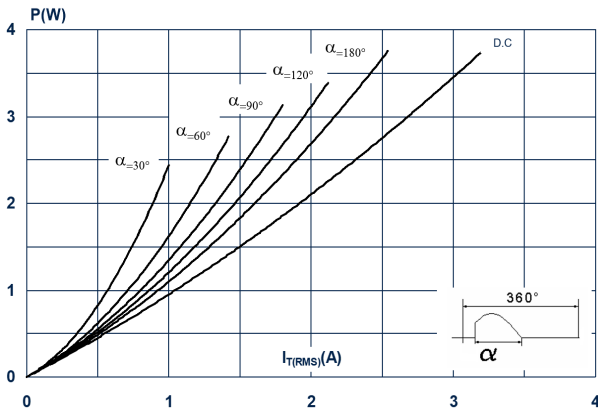


Figure 2. Average and DC on-state current versus case temperature

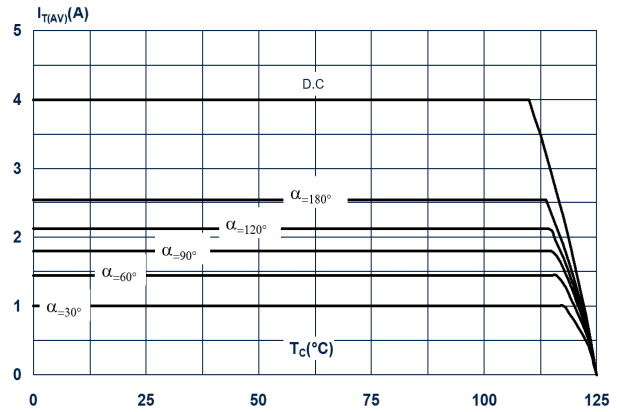


Figure 3. On-state RMS current versus ambient temperature (full cycle)

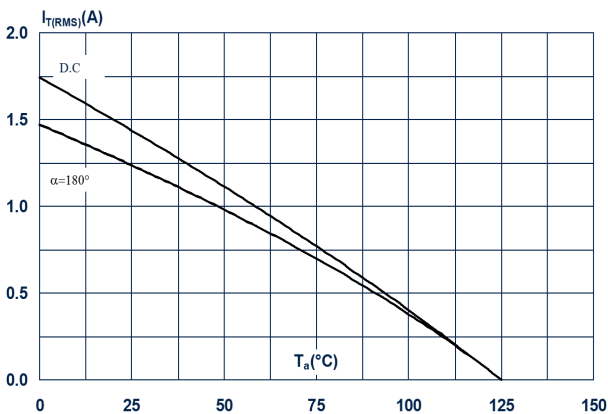


Figure 4. Relative variation of thermal impedance versus pulse duration

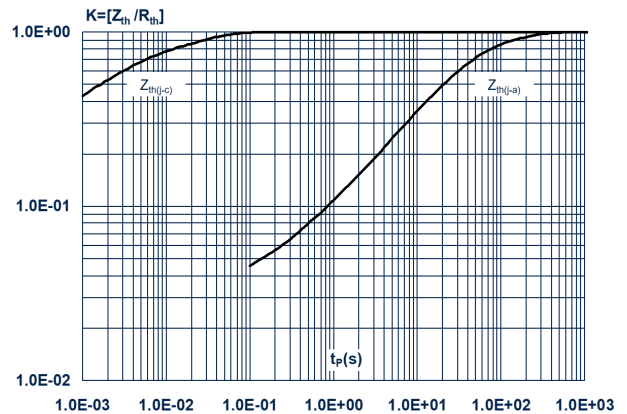


Figure 5. Relative variation of gate triggering current and voltage versus junction temperature (typical values)

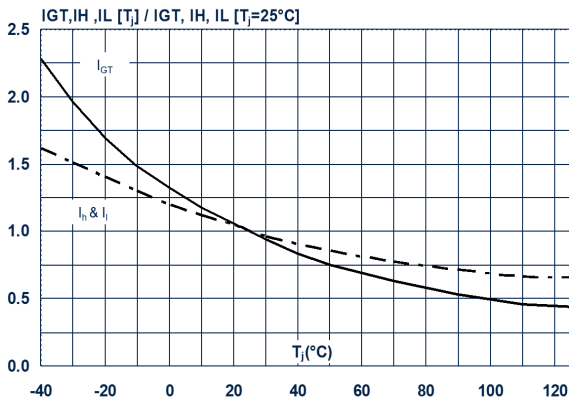


Figure 6. Surge peak on-state current versus number of cycles

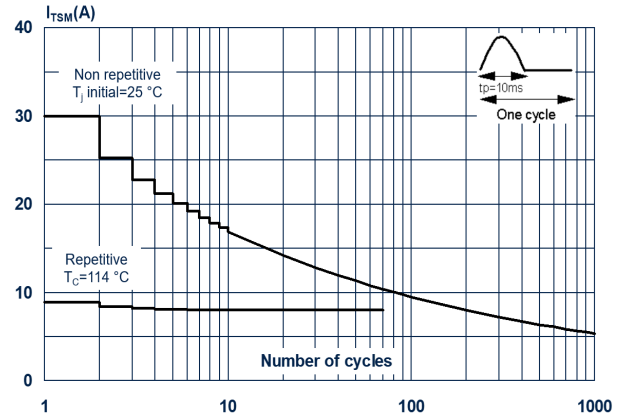


Figure 7. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms and corresponding value of I^2t

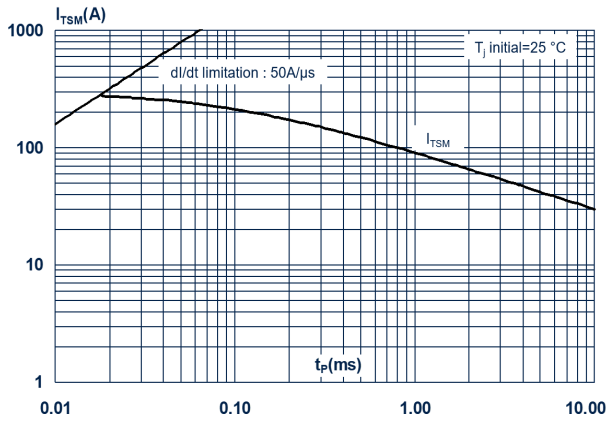


Figure 8. On-state characteristics (maximum values)

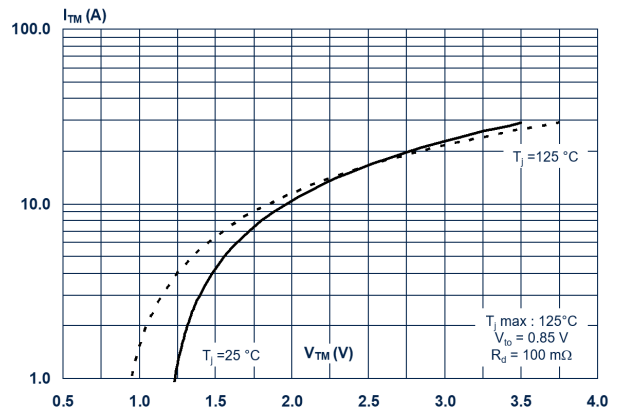


Figure 9. Relative variation of static dV/dt immunity versus gate-to-cathode resistance (typical values)

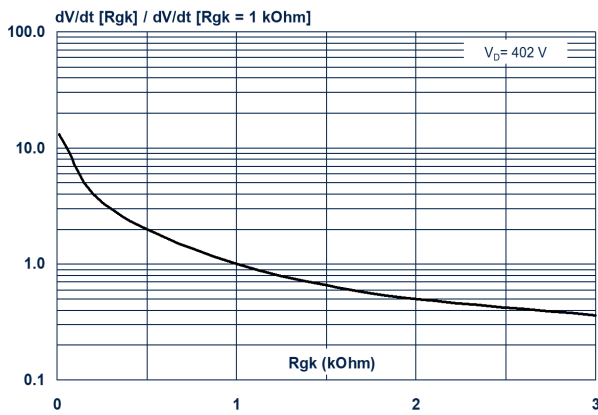


Figure 10. Relative variation of static dV/dt immunity versus gate-to-cathode capacitance (typical values)

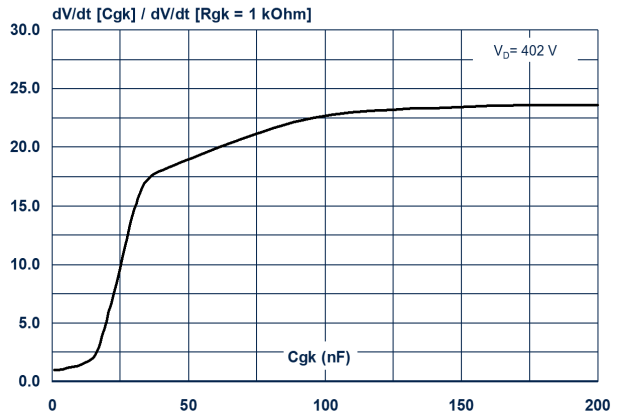


Figure 11. Relative variation of static dV/dt immunity versus junction temperature

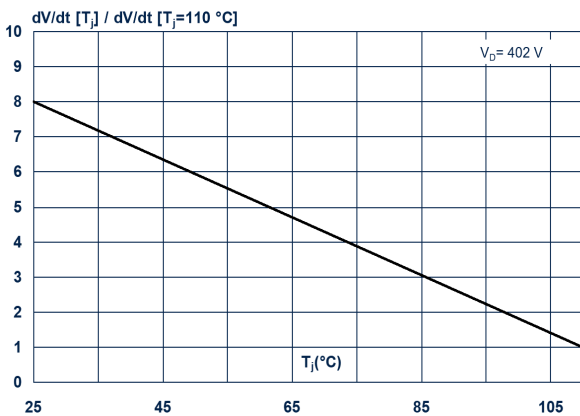
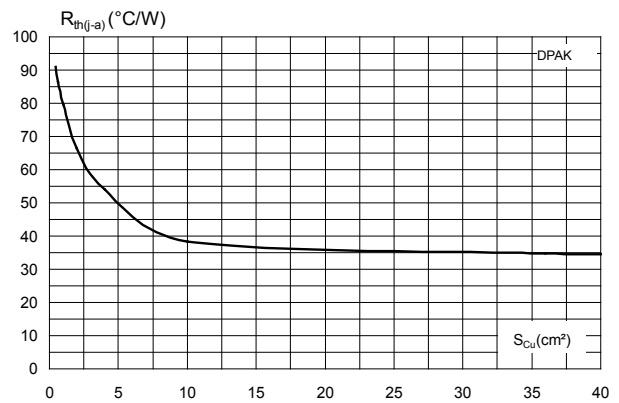


Figure 12. Thermal resistance junction to ambient versus copper surface under tab (typical values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 DPAK package information

- Molding compounded resin is halogen free and meets UL94 flammability standard, level V0
- Lead-free package leads plating

Figure 13. DPAK package outline

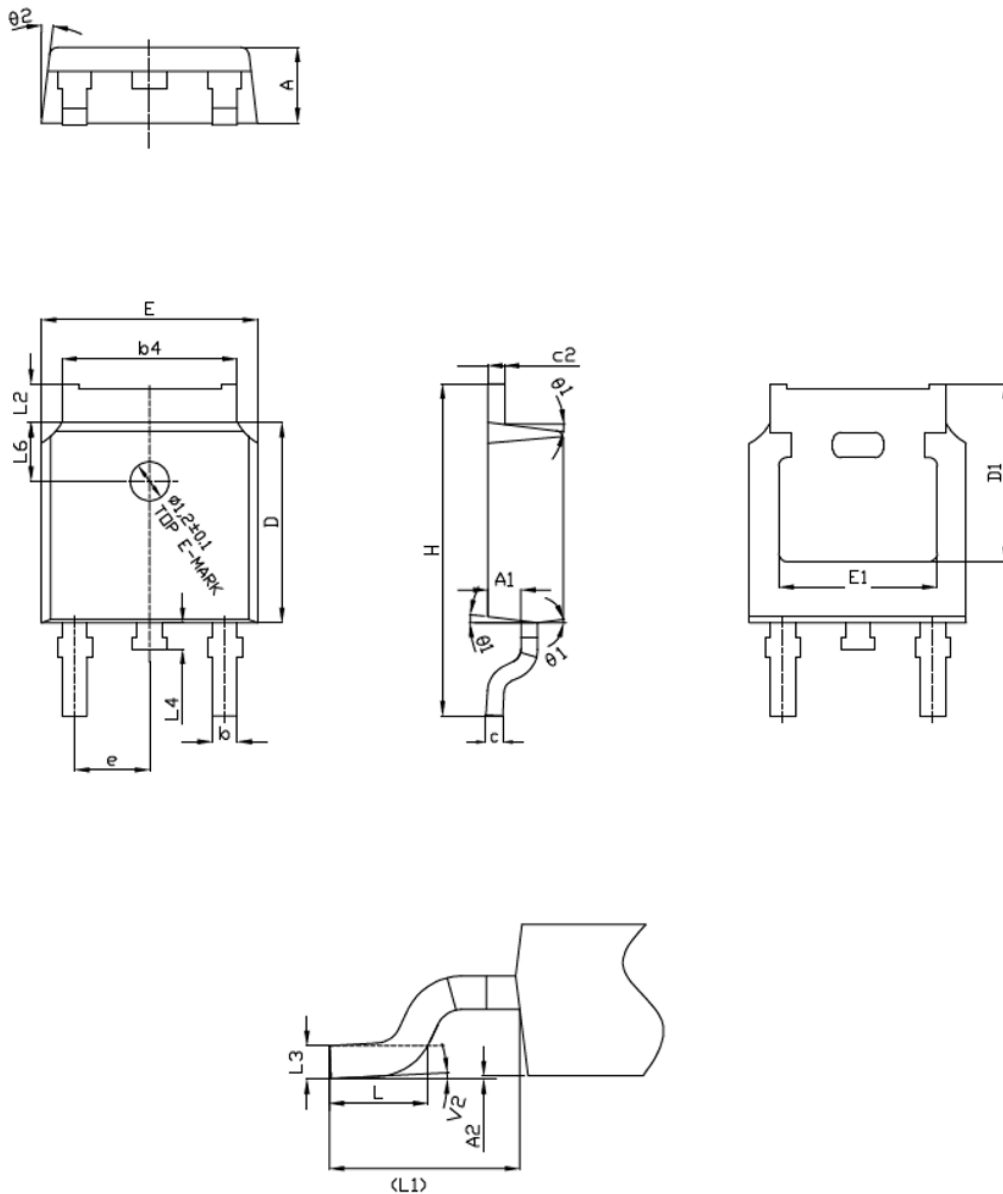


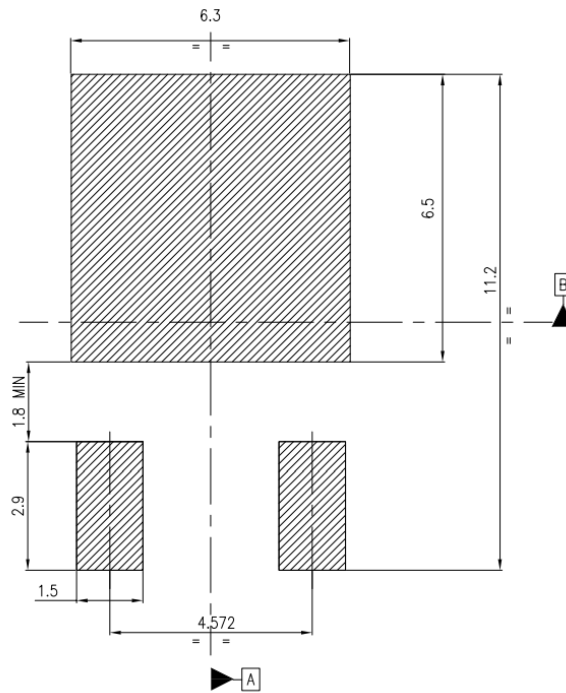
Table 5. DPAK package mechanical data

Ref.	Dimensions					
	Millimeters			Inches ⁽¹⁾		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.20	2.30	2.38	0.0866	0.0906	0.0937
A1	0.90	1.01	1.10	0.0354	0.0398	0.0433
A2	0.00		0.10	0.0000		0.0039
b	0.72		0.85	0.0283		0.335
b4	5.13	5.33	5.46	0.2020	0.2098	0.2150
c	0.47		0.60	0.0185		0.0236
c2	0.47		0.60	0.0185		0.0236
D	6.00	6.10	6.20	0.2362	0.2402	0.2441
D1	5.15	5.40	5.65	0.2028	0.2126	0.2224
E	6.50	6.60	6.70	0.2550	0.2598	0.2638
E1	4.70	4.85	5.00	0.1850	0.1909	0.1969
e	2.186	2.286	2.386	0.0860	0.0900	0.0940
H	9.80	10.10	10.40	0.3858	0.3976	0.4094
L	1.40	1.50	1.70	0.0551	0.0591	0.0669
L1	2.90 REF			0.1142 REF		
L2	0.90		1.25	0.0354		0.0492
L3	0.51 BSC			0.201 BSC		
L4	0.60	0.80	1.00	0.0236	0.0315	0.0394
L6	1.80 BSC			0.0709 BSC		
Θ1	5°	7°	9°	5°	7°	9°
Θ2	5°	7°	9°	5°	7°	9°
V2	0°		8°	0°		8°

1. Dimensions in inches are given for reference only

Note: This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Figure 14. DPAK recommended footprint (dimensions are in mm)



3 Ordering information

Figure 15. Ordering information scheme

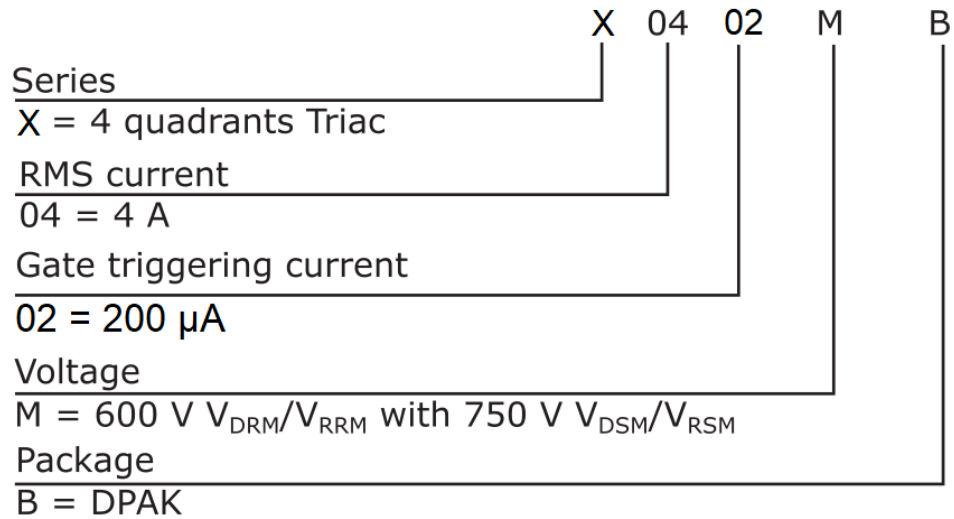


Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
X0402MB	X0402MB	DPAK	0.3 g	2500	Tape and reel

Revision history

Table 7. Document revision history

Date	Revision	Changes
06-Sep-2022	1	Initial release.

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